

TECHNICAL DATA DATA SHEET 4764, REV. –

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HERMETIC POWER SCHOTTKY RECTIFIER

Low Forward Voltage Drop

Add Suffix "S" to Part Number for S-100 Screening.

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability

DESCRIPTION: A 150-VOLT, 30/15 AMP DUAL POWER SCHOTTKY RECTIFIER IN A HERMETIC SHD-4/4A/4B PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	150	Volts
MAXIMUM DC OUTPUT CURRENT (@ T _C =100 ^O C) (Single, Doubler)	Io	15	Amps
MAXIMUM DC OUTPUT CURRENT (@ T _C =100 °C) (Common Cathode, Common Anode)	lo	30	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=8.3ms, Sine)	I _{FSM}	280	Amps
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{ heta JC}$	0.4	°C/W
MAXIMUM OPERATING TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C
MAXIMUM STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C

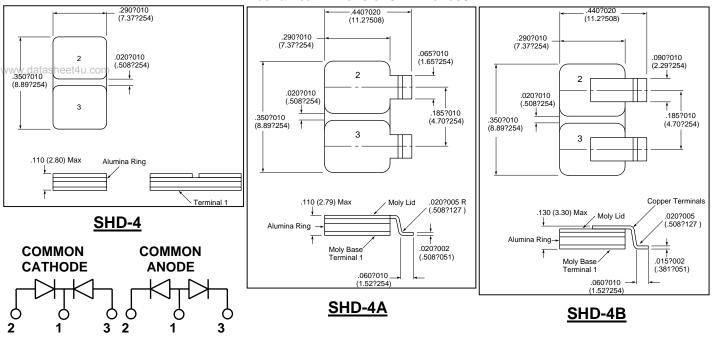
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 15 Amps)			
$T_J = 25$ °C $T_J = 125$ °C	V_{f}	0.88 0.72	Volts
MAXIMUM REVERSE CURRENT (I _r @ 150V PIV)			
$T_J = 25$ °C $T_J = 125$ °C	l _r	0.5 8	mA
MAXIMUM JUNCTION CAPACITANCE (V _r =5V) C _T	500	pF

SENSITRON

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Mechanical Dimensions: In Inches / mm



PINOUT TABLE			
DEVICE TYPE	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER, COMMON CATHODE (P)	COMMON CATHODE	ANODE 1	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	COMMON ANODE	CATHODE 1	CATHODE 2



TECHNICAL DATA

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